Francesco Barreca

List of Publications by Year in descending order

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20 papers 385

12 h-index

759233

19 g-index

20 all docs

20 docs citations

20 times ranked 646 citing authors

#	Article	IF	CITATIONS
1	Electrospun Ag/PMA Nanofibrous Scaffold as a Drug Delivery System. Current Nanomaterials, 2019, 4, 32-38.	0.4	4
2	Molybdenum oxide nanocolloids prepared by an external field-assisted laser ablation in water. EPJ Web of Conferences, 2018, 167, 04009.	0.3	6
3	PEG-PLGA electrospun nanofibrous membranes loaded with Au@Fe2O3 nanoparticles for drug delivery applications. Frontiers of Physics, 2018, 13, 1.	5.0	17
4	Low cost tips for tip-enhanced Raman spectroscopy fabricated by two-step electrochemical etching of 125 µm diameter gold wires. Beilstein Journal of Nanotechnology, 2018, 9, 2718-2729.	2.8	13
5	Nanoscale Discrimination between Toxic and Nontoxic Protein Misfolded Oligomers with Tipâ€Enhanced Raman Spectroscopy. Small, 2018, 14, e1800890.	10.0	35
6	Template Electrochemical Growth and Properties of Mo Oxide Nanostructures. Journal of Physical Chemistry C, 2014, 118, 22299-22308.	3.1	33
7	Mesoporous carbon–silica solid acid catalysts for producing useful bio-products within the sugar-platform of biorefineries. Green Chemistry, 2014, 16, 4292-4305.	9.0	62
8	Influence of the plasma expansion dynamics on the structural properties of pulsed laser ablation deposited tin oxide thin films. Thin Solid Films, 2010, 518, 5409-5415.	1.8	14
9	Investigation of a nanocrystalline silicon phase embedded in SiO[sub x] thin films grown by pulsed laser deposition. Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena, 2005, 23, 519.	1.6	20
10	Time resolved imaging studies of the plasma produced by laser ablation of silicon in O2/Ar atmosphere. Laser and Particle Beams, 2005, 23, 149-153.	1.0	29
11	Pulsed laser ablation of SiC in a nitrogen atmosphere: formation of CN. Applied Physics A: Materials Science and Processing, 2004, 79, 1997-2005.	2.3	25
12	Electronic properties of PLD prepared nitrogenated a-SiC thin films. Thin Solid Films, 2003, 433, 34-38.	1.8	8
13	Bonding configurations and optical band gap for nitrogenated amorphous silicon carbide films prepared by pulsed laser ablation. Journal of Applied Physics, 2002, 92, 2485-2489.	2.5	26
14	Excimer laser ablation of silicon carbide ceramic targets. Diamond and Related Materials, 2002, 11, 273-279.	3.9	21
15	Characterization of pulsed laser deposited a-C films by means of reflection electron energy loss spectroscopy. Thin Solid Films, 2001, 398-399, 228-232.	1.8	9
16	Optical constants of CNx thin films from reflection electron energy loss spectroscopy. Thin Solid Films, 2000, 377-378, 631-634.	1.8	12
17	Measurement of the dielectric constant of amorphousCNxfilms in the 0–45 eV energy range. Physical Review B, 2000, 62, 16893-16899.	3.2	14
18	Raman microscopy study of pulsed laser ablation deposited silicon carbide films. Thin Solid Films, 1998, 332, 290-294.	1.8	30

#	Article	IF	CITATIONS
19	Micro-Raman study of reactive pulsed laser ablation deposited silicon carbon alloy films. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 1998, 16, 3020-3024.	2.1	4
20	Laser Ablation-Deposited CN x Thin Films. , 0, , 287-302.		3